BLM7G1822S-40PB; BLM7G1822S-40PBG LDMOS 2-stage power MMIC

AMMPLEON

Rev. 5 — 24 February 2016

Product data sheet

Product profile

1.1 General description

The BLM7G1822S-40PB(G) is a dual section, 2-stage power MMIC using Ampleon's state of the art GEN7 LDMOS technology. This multiband device is perfectly suited as general purpose driver or small cell final in the frequency range from 1805 MHz to 2170 MHz. Available in gull wing or straight lead outline.

Application performance Table 1.

Typical RF performance at T_{case} = 25 °C; I_{Dq1} = 40 mA; I_{Dq2} = 120 mA.

Test signal: 3GPP test model 1; 64 DPCH; PAR = 10 dB at 0.01% probability on CCDF; per section unless otherwise specified in a class-AB production circuit.

Test signal	f	V _{DS}	P _{L(AV)}	G _p	η_{D}	ACPR _{5M}
	(MHz)	(V)	(W)	(dB)	(%)	(dBc)
single carrier W-CDMA	2167.5	28	4	31.5	25	-38.5

1.2 Features and benefits

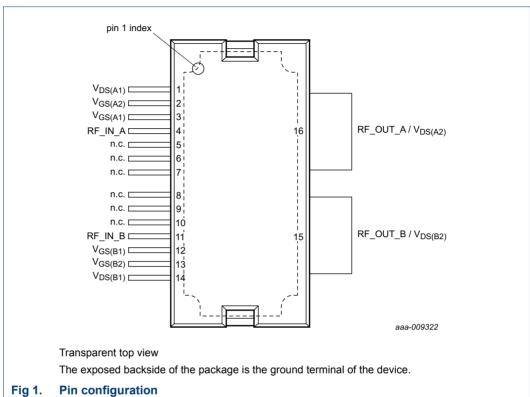
- Designed for broadband operation (frequency 1805 MHz to 2170 MHz)
- High section-to-section isolation enabling multiple combinations
- Integrated temperature compensated bias
- Biasing of individual stages is externally accessible
- Integrated ESD protection
- Excellent thermal stability
- High power gain
- On-chip matching for ease of use
- Compliant to Directive 2002/95/EC, regarding restriction of hazardous substances (RoHS)

1.3 Applications

- RF power MMIC for W-CDMA base stations in the 1805 MHz to 2170 MHz frequency range. Possible circuit topologies are the following as also depicted in Section 8.1:
 - Dual section or single ended
 - Dohertv
 - Quadrature combined
 - Push-pull

Pinning information 2.

Pinning 2.1



2.2 Pin description

Pin description Table 2.

Symbol	Pin	Description
V _{DS(A1)}	1	drain-source voltage of stage A1
V _{GS(A2)}	2	gate-source voltage of stage A2
V _{GS(A1)}	3	gate-source voltage of stage A1
RF_IN_A	4	RF input section A
n.c.	5	not connected
n.c.	6	not connected
n.c.	7	not connected
n.c.	8	not connected
n.c.	9	not connected
n.c.	10	not connected
RF_IN_B	11	RF input section B
V _{GS(B1)}	12	gate-source voltage of stage B1
V _{GS(B2)}	13	gate-source voltage of stage B2
V _{DS(B1)}	14	drain-source voltage of stage B1

Table 2. Pin description ...continued

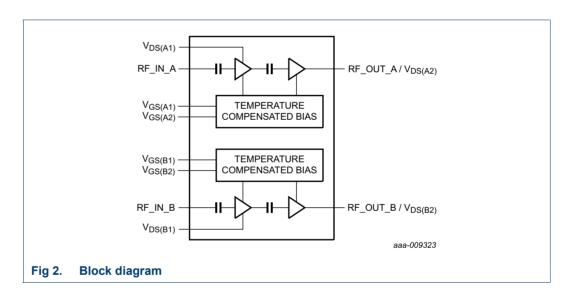
Symbol	Pin	Description
RF_OUT_B/V _{DS(B2)}	15	RF output section B / drain-source voltage of stage B2
RF_OUT_A/V _{DS(A2)}	16	RF output section A / drain-source voltage of stage A2
GND	flange	RF ground

3. Ordering information

Table 3. Ordering information

Type number	Package	ckage							
	Name	ame Description							
BLM7G1822S-40PB	HSOP16F	plastic, heatsink small outline package; 16 leads (flat)	SOT1211-2						
BLM7G1822S-40PBG	HSOP16	plastic, heatsink small outline package; 16 leads	SOT1212-2						

4. Block diagram



5. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	65	V
V_{GS}	gate-source voltage		-0.5	+13	V
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature	[1]	-	225	°C
T _{case}	case temperature		-	150	°C

^[1] Continuous use at maximum temperature will affect the reliability. For details refer to the online MTF calculator.

6. Thermal characteristics

Table 5. Thermal characteristics

Measured for total device.

Symbol	Parameter	Conditions	Value	Unit
R _{th(j-c)}	thermal resistance from junction to case	final stage; $T_{case} = 90 ^{\circ}C$; $P_{L} = 2.52 W$	1.2	K/W
		driver stage; T _{case} = 90 °C; P _L = 2.52 W	3.8	K/W

^[1] When operated with a CW signal.

7. Characteristics

Table 6. DC characteristics

 T_{case} = 25 °C; per section unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Final stag	je					-	
V _{(BR)DSS}	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 0.302 \text{ mA}$		65	-	-	V
V _{GS(th)}	gate-source threshold voltage	V _{DS} = 10 V; I _D = 30.2 mA		1.4	1.8	2.4	V
V_{GSq}	gate-source quiescent voltage	V _{DS} = 28 V; I _D = 120 mA		1.55	1.9	2.45	V
		V _{DS} = 28 V; I _D = 120 mA	[1]	1.9	2.3	3.3	V
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 28 V		-	-	1.4	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V}; V_{DS} = 10 \text{ V}$		-	5.4	-	Α
I _{GSS}	gate leakage current	V _{GS} = 1.0 V; V _{DS} = 0 V		-	-	140	nA
Driver sta	ige					1	
V _{(BR)DSS}	drain-source breakdown voltage	V _{GS} = 0 V; I _D = 0.058 mA		65	-	-	V
V _{GS(th)}	gate-source threshold voltage	V _{DS} = 10 V; I _D = 5.8 mA		1.4	1.8	2.4	V
V_{GSq}	gate-source quiescent voltage	V _{DS} = 28 V; I _D = 40 mA		1.65	2	2.55	V
		V _{DS} = 28 V; I _D = 40 mA	[2]	1.9	2.4	3.2	V
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 28 V		-	-	1.4	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V}; V_{DS} = 10 \text{ V}$		-	1.04	-	Α
I _{GSS}	gate leakage current	V _{GS} = 1.0 V; V _{DS} = 0 V		-	-	140	nA

^[1] In production circuit with 825 Ω gate feed resistor.

^[2] In production circuit with 850 Ω gate feed resistor.

Table 7. RF Characteristics

Typical RF performance at T_{case} = 25 °C; V_{DS} = 28 V; I_{Dq1} = 40 mA; I_{Dq2} = 120 mA; $P_{L(AV)}$ = 4 W. Per section unless otherwise specified, measured in an Ampleon wideband f = 1807.5 MHz to 2167.5 MHz production circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Test signa	ll: single carrier W-CDMA [1]		'			
Gp	power gain	f = 1807.5 MHz	-	31	-	dB
		f = 2167.5 MHz	30	31.5	33	dB
η _D	drain efficiency	f = 1807.5 MHz	-	24.5	-	%
		f = 2167.5 MHz	22	25	-	%
RLin	input return loss	f = 2167.5 MHz	-	-15	-10	dB
ACPR _{5M}	adjacent channel power ratio (5 MHz)	f = 1807.5 MHz	-	-40.5	-	dBc
		f = 2167.5 MHz	-	-38.5	-36.5	dBc
PAR _O	output peak-to-average ratio	f = 1807.5 MHz	-	8	-	dB
		f = 2167.5 MHz	7.2	7.7	-	dB
$\Delta I_{Dq}/\Delta T$	quiescent drain current variation with	T = -40 °C to +85 °C				
	temperature	final stage I_{Dq} ; gate feed resistor = 825 Ω	-	±1	-	%
		driver stage I_{Dq} ; gate feed resistor = 850 Ω	-	±1	-	%
Test signa	I: CW [2]		'	,	,	
$\Delta \phi_{s21}$	phase response difference	between sections	-10	-	+10	deg
$\Delta s_{21} ^2$	insertion power gain difference	between sections	-0.5	-	+0.5	dB

^{[1] 3}GPP test model 1; 64 DPCH; PAR = 10 dB at 0.01% probability on CCDF.

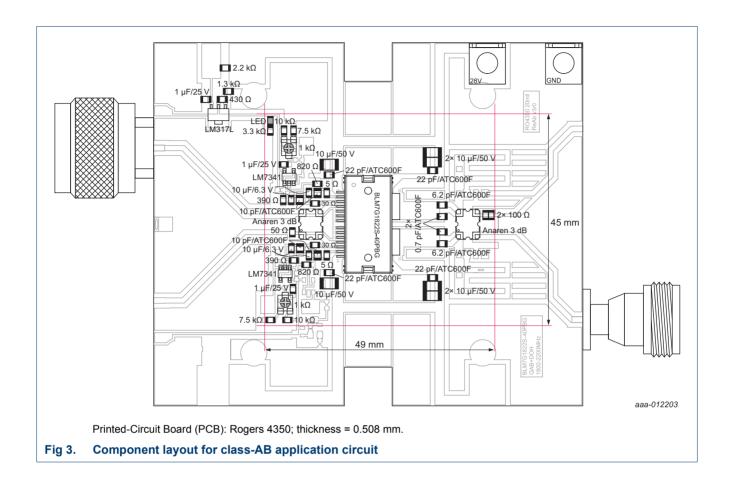
8. Application information

Table 8. Typical performance

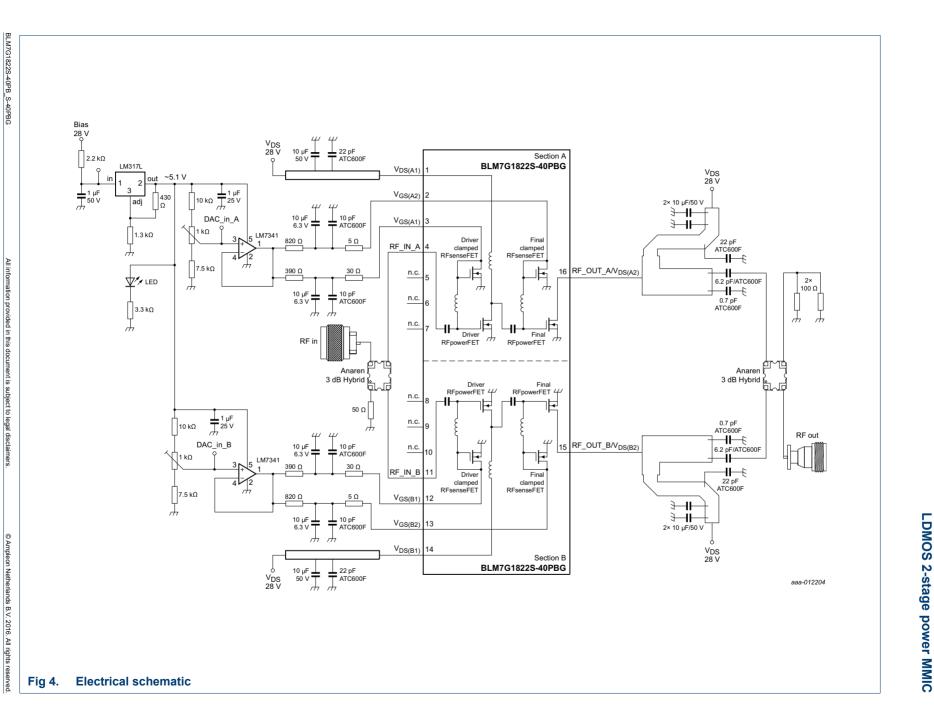
Test signal: 1-tone CW; RF performance at $T_{\rm case}$ = 25 °C; V_{DS} = 28 V; I_{Dq1} = 80 mA (both sections); I_{Dq2} = 240 mA (both sections) unless otherwise specified, measured in an Ampleon wideband f = 1805 MHz to 2170 MHz class AB application circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
P _{L(1dB)}	output power at 1 dB gain compression	f = 1960 MHz	-	45.1	-	W
η_{D}	drain efficiency	at P _{L(1dB)} ; f = 1960 MHz	-	53.3	-	%
G _p	power gain	P _{L(AV)} = 4 W; f = 1960 MHz	-	31.6	-	dB
B _{video}	video bandwidth	2-tone CW; P _{L(AV)} = 4 W; f = 1960 MHz	-	140	-	MHz
G _{flat}	gain flatness	P _{L(AV)} = 4 W	-	0.2	-	dB
ΔG/ΔΤ	gain variation with temperature	f = 1960 MHz	-	0.03	-	dB/°C
S ₁₂ ²	isolation	between sections A and B; P _{L(AV)} = 4 W; f = 1960 MHz	-	27.8	-	dB
K	Rollett stability factor	T = -40 °C; f = 0.1 GHz to 3 GHz	-	>1	-	

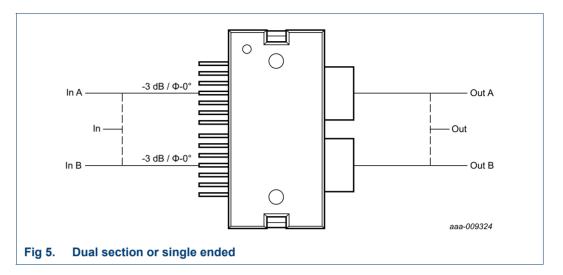
^[2] f = 2170 MHz.

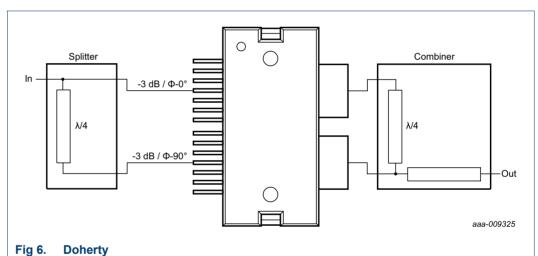


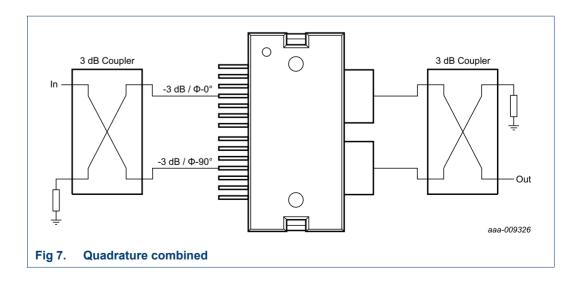
Product data sheet

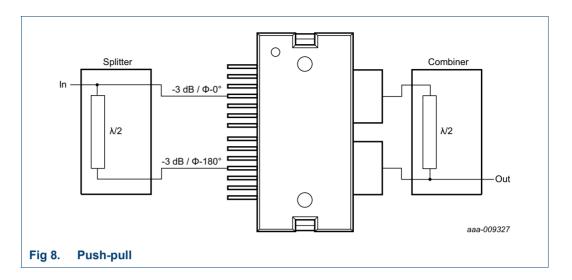


8.1 Possible circuit topologies









8.2 Ruggedness in class-AB operation

The BLM7G1822S-40PB and BLM7G1822S-40PBG are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 28 V; I_{Dq1} = 80 mA; I_{Dq2} = 240 mA; P_i = 16 dBm (CW); f = 2140 MHz.

8.3 Impedance information

 t_p = 100 μ s; δ = 10 %; Z_S = 50 Ω . Typical values unless otherwise specified.

Table 9. Typical impedance tuned for maximum output power

Measured load-pull data per section; test signal: pulsed CW; $T_{case} = 25 \, ^{\circ}\text{C}$; $V_{DS} = 28 \, \text{V}$; $I_{Dq1} = 40 \, \text{mA}$; $I_{Dq2} = 110 \, \text{mA}$;

	at 1dB gain	compress	ion poi	int		at 3dB gain compression point					
f	Z _L	G _{p(max)}	PL	η _{add}	AM-PM conversion	Z _L	G _{p(max)}	PL	η _{add}	AM-PM conversion	
(MHz)	(Ω)	(dB)	(W)	(%)	(deg)	(Ω)	(dB)	(W)	(%)	(deg)	
BLM7G1	1822S-40PB				"		1		'	'	
1805	7.2 – j9.2	32.2	45	48.3	1.7	7.7 – j10.6	32.2	45.8	51	0.3	
1842.5	7.2 – j9.2	32.3	45	49	2.3	7.8 – j10.6	32.3	45.8	51.8	0.9	
1880	7.2 – j9.2	32.4	44.9	49.9	2.7	7.7 – j10.6	32.3	45.8	52.1	1.4	
1930	7.3 – j9.2	32.5	44.9	50.5	1.8	6.7 – j10.8	32	45.7	48.8	0.3	
1960	7.2 – j9.2	32.7	45	50.8	3.3	7.8 – j10.6	32.6	45.7	51.4	1.6	
1990	7.2 – j9.2	32.8	45	51	3.3	6.3 – j9.5	32.5	45.7	49.1	0.5	
2110	6.3 – j9.5	33	45.2	50.7	2.2	6.3 – j9.5	33	45.8	51.4	-4	
2140	6.3 – j9.5	33	45.1	50.7	1.2	6.3 – j9.5	33	45.7	51.8	-5.9	
2170	6.3 – j9.5	33	45.1	51.3	0.3	6.8 – j10.8	32.8	45.6	50.1	-7.5	
BLM7G1	1822S-40PBG								,		
1805	8.7 – j11.9	32.1	45	50.8	-0.2	8.0 – j13.4	31.8	45.8	50.3	-1.7	
1842.5	8.7 – j11.8	32.3	45	50.6	0.4	8.0 – j13.4	31.9	45.8	49.2	-1	
1880	7.5 – j12.0	32.1	45	48.6	1.4	8.0 – j13.4	32.1	45.8	50	-0.3	
1930	8.0 – j13.4	32.1	45	48.7	1.6	8.0 – j13.4	32.1	45.8	50.3	-0.6	
1960	7.5 – j12.1	32.5	45	49.5	1.7	8.0 – j13.4	32.4	45.7	49.9	-0.4	

Table 9. Typical impedance tuned for maximum output power ...continued

Measured load-pull data per section; test signal: pulsed CW; T_{case} = 25 °C; V_{DS} = 28 V; I_{Dq1} = 40 mA; I_{Dq2} = 110 mA; I_{p} = 100 μs; δ = 10 %; I_{q} = 50 I_{q} . Typical values unless otherwise specified.

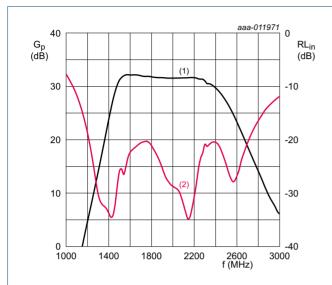
	at 1dB gain compression point					at 3dB gain compression point				
f	Z _L	G _{p(max)}	PL	η _{add}	AM-PM conversion	Z _L	G _{p(max)}	PL	η _{add}	AM-PM conversion
(MHz)	(Ω)	(dB)	(W)	(%)	(deg)	(Ω)	(dB)	(W)	(%)	(deg)
1990	8.0 – j13.3	32.6	45	49	2.4	7.7 – j15.2	32.2	45.7	47	-0.7
2110	8.1 – j13.4	33	45.2	51	0.8	8.1 – j13.4	33	45.8	52.1	-6.1
2140	6.5 – j12.8	32.7	45.1	49.9	-0.8	6.5 – j12.8	32.7	45.7	50.8	-8.9
2170	7.0 – j14.1	32.4	45.1	48.3	-1.5	7.0 – j14.1	32.4	45.6	49.1	-10

Table 10. Typical impedance tuned for maximum power added efficiency

Measured load-pull data per section; test signal: pulsed CW; T_{case} = 25 °C; V_{DS} = 28 V; I_{Dq1} = 40 mA; I_{Dq2} = 110 mA; I_{Dq2} = 100 μs; δ = 10 %; I_{Dq3} = 50 I_{Dq3} . Typical values unless otherwise specified.

	at 1dB gain		at 3dB gain compression point							
f	Z _L	C _L G _{p(max)}	nax) P _L η _{add}	η _{add}	AM-PM conversion	Z _L	G _{p(max)}	P _L	η _{add}	AM-PM conversion
(MHz)	(Ω)	(dB)	(W)	(%)	(deg)	(Ω)	(dB)	(W)	(%)	(deg)
BLM7G	1822S-40PB							1		
1805	18.0 – j7.9	33.4	43.1	57.8	-0.6	16.7 – j4.2	33.5	43.9	58.8	-4.9
1842.5	16.6 – j4.0	33.5	43	58	-1.1	16.2 – j5.6	33.4	44	58.5	-3
1880	14.2 – j5.6	33.4	43.6	57.9	0.4	12.2 – j4.6	33.4	44.5	58.4	-2.8
1930	11.6 – j3.4	33.5	43.4	57.5	-1.6	11.6 – j3.4	33.5	44.1	57.7	-4.3
1960	9.9 – j4.4	33.6	43.9	57.5	0.3	9.9 – j4.4	33.6	44.6	57.6	-2.3
1990	10.8 – j3.1	33.7	43.4	57.4	0.2	8.6 – j4.3	33.6	44.6	57	-3.1
2110	7.3 – j4.8	33.8	43.9	57.5	-0.2	7.3 – j4.8	33.8	44.6	56.4	-4.4
2140	7.3 – j4.8	33.8	43.9	57.5	-0.5	7.3 – j4.8	33.8	44.5	56.2	-5.4
2170	7.0 – j6.3	33.6	44.3	57.2	-0.3	7.0 – j6.3	33.6	44.9	56.5	-7
BLM7G	1822S-40PBG				,			1	1	-
1805	18.8 – j9.7	33	43.2	57.4	-2.4	14.8 – j8.7	33	44.6	58.1	-5.5
1842.5	16.9 – j6.3	33.2	43.2	57.4	-2.7	16.3 – j4.3	33.3	44.7	57.5	-7.4
1880	15.3 – j5.5	33.3	43.2	57.2	-1.9	12.7 – j7.1	33.2	44.5	57.3	-4.3
1930	12.8 – j7.3	33.2	43.7	56.7	-0.9	12.8 – j7.3	33.2	44.4	56.3	-3.4
1960	11.1 – j6.8	33.5	43.8	56.5	-1	11.1 – j6.8	33.5	44.5	56.1	-3.6
1990	9.6 – j6.5	33.5	43.7	56.3	-0.9	9.0 – j7.7	33.4	44.8	55.9	-3.4
2110	9.0 – j7.7	33.7	44	57.1	-0.4	7.6 – j8.0	33.6	44.7	56.1	-6.7
2140	8.1 – j6.7	33.6	43.5	56.9	-1.6	7.6 – j8.0	33.5	44.5	55.7	-7.7
2170	6.4 – j7.7	33.3	43.6	57.2	-3	8.6 – j9.0	33.3	44.8	55.8	-7.8

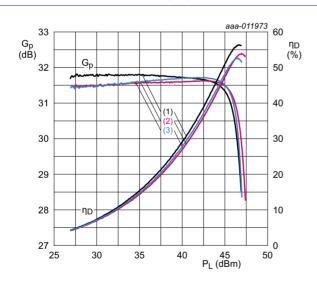
8.4 Graphs



 T_{case} = 25 °C; V_{DS} = 28 V; I_{Dq1} = 40 mA; I_{Dq2} = 120 mA; P_{I} = 4 W. Per section.

- (1) magnitude of G_p
- (2) magnitude of RLin

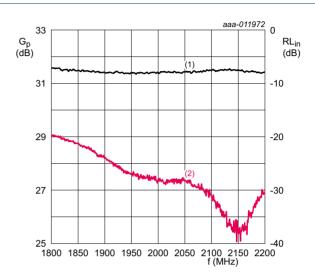
Fig 9. Wideband power gain and input return loss as function of frequency; typical values



 T_{case} = 25 °C; V_{DS} = 28 V; I_{Dq1} = 40 mA; I_{Dq2} = 120 mA. Per section.

- (1) f = 1805 MHz
- (2) f = 1960 MHz
- (3) f = 2170 MHz

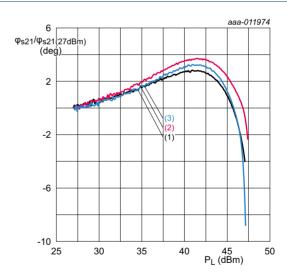
Fig 11. Power gain and drain efficiency as function of output power; typical values



 T_{case} = 25 °C; V_{DS} = 28 V; I_{Dq1} = 40 mA; I_{Dq2} = 120 mA; P_{I} = 4 W. Per section.

- (1) magnitude of G_p
- (2) magnitude of RLin

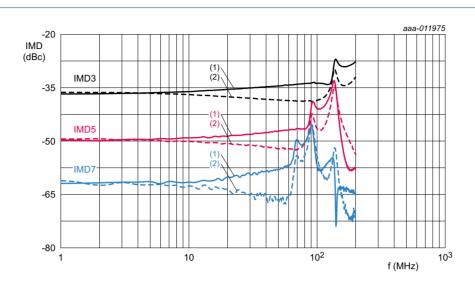
Fig 10. In-band power gain and input return loss as function of frequency; typical values



 T_{case} = 25 °C; V_{DS} = 28 V; I_{Dq1} = 40 mA; I_{Dq2} = 120 mA. Per section.

- (1) f = 1805 MHz
- (2) f = 1960 MHz
- (3) f = 2170 MHz

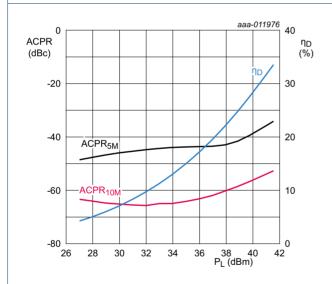
Fig 12. 27 dBm normalized phase response as a function of output power; typical values



 T_{case} = 25 °C; V_{DS} = 28 V; I_{Dq1} = 40 mA; I_{Dq2} = 120 mA; f = 1960 MHz; 2-tone CW; $P_{L(AV)}$ = 4 W. Per section.

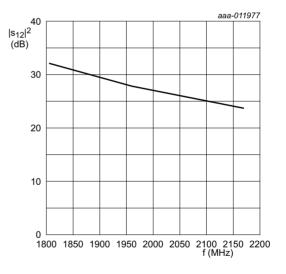
- (1) IMD low
- (2) IMD high

Fig 13. Intermodulation distortion as a function of tone spacing; typical values



 T_{case} = 25 °C; V_{DS} = 28 V; I_{Dq1} = 40 mA; I_{Dq2} = 120 mA; f = 1960 MHz; 1-carrier W-CDMA; test model 1; PAR = 7.2 dB at 0.01 % probability on CCDF. Per section.

Fig 14. Adjacent channel power ratio and drain efficiency as function of output power; typical values



 T_{case} = 25 °C; V_{DS} = 28 V; I_{Dq1} = 40 mA; I_{Dq2} = 120 mA. Per section.

Fig 15. Isolation as a function of frequency; typical values

9. Package outline

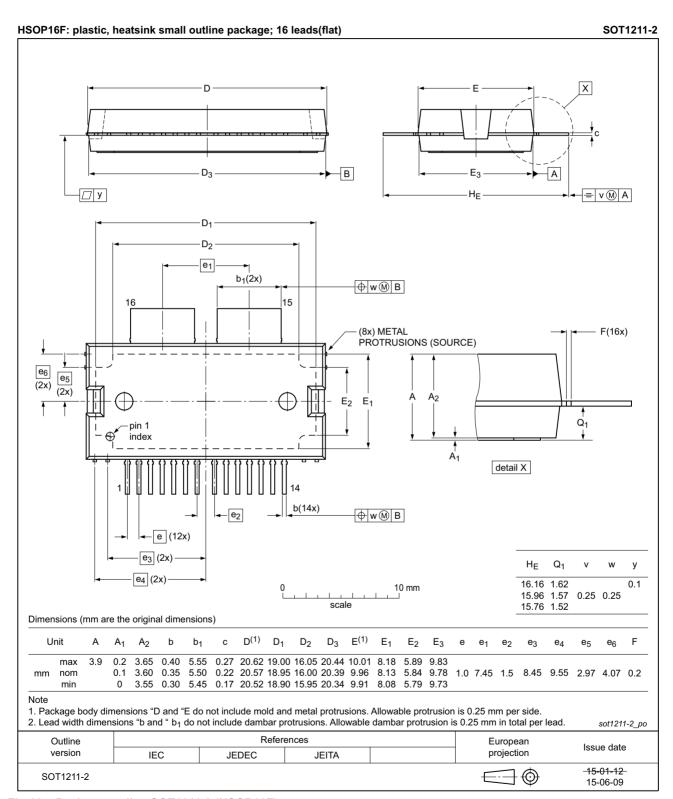


Fig 16. Package outline SOT1211-2 (HSOP16F)

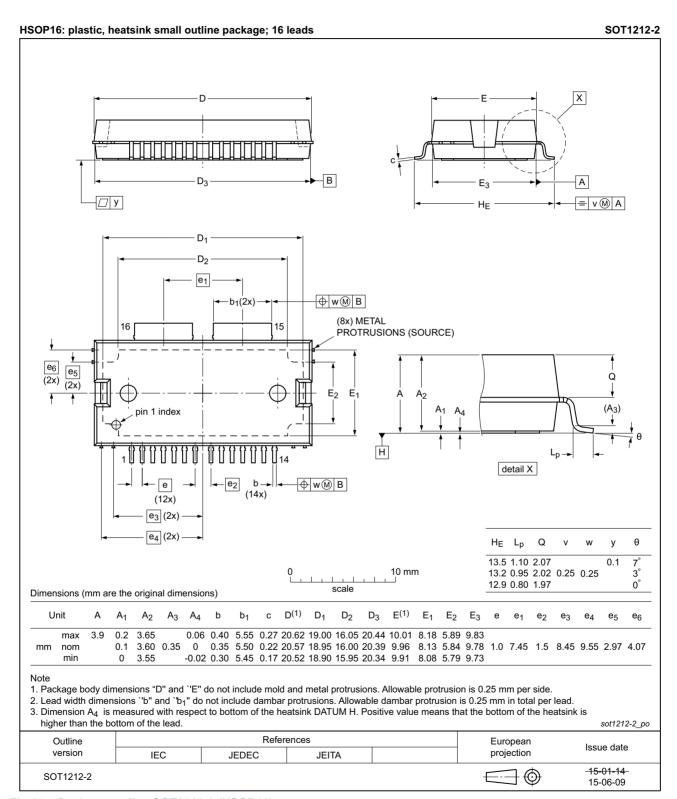


Fig 17. Package outline SOT1212-2 (HSOP16)

10. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

11. Abbreviations

Table 11. Abbreviations

Acronym	Description
AM	Amplitude Modulation
3GPP	3rd Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
ESD	ElectroStatic Discharge
GEN7	Seventh Generation
LDMOS	Laterally Diffused Metal Oxide Semiconductor
MMIC	Monolithic Microwave Integrated Circuit
MTF	Median Time to Failure
PAR	Peak-to-Average Ratio
PM	Phase Modulation
VSWR	Voltage Standing-Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

12. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLM7G1822S-40PB_S-40PBG v.5	20160224	Product data sheet		BLM7G1822S-40PB_S -40PBG v.4
Modifications:	Table 6 on	page 4: table updated		
BLM7G1822S-40PB_S-40PBG v.4	20150901	Product data sheet		BLM7G1822S-40PB_S -40PBG v.3
BLM7G1822S-40PB_S-40PBG v.3	20150701	Product data sheet	-	BLM7G1822S-40PB_ S-40PBG v.2
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13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.ampleon.com.

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